

BCR10PM-14LJ

700V - 10A - Triac
Medium Power Use

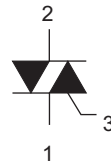
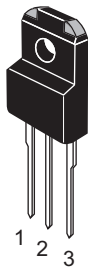
R07DS0980EJ0100
Rev.1.00
Dec 03, 2012

Features

- $I_{T(RMS)}$: 10 A
- V_{DRM} : 800 V ($T_j = 125^\circ\text{C}$)
- T_j : 150 °C
- I_{FGTB} , I_{RGTB} , I_{RGTH} : 30 mA
- Viso: 2000V
- Insulated Type
- Planar Passivation Type
- UL Recognized: File No. E223904

Outline

RENESAS Package code: PRSS0003AA-A
(Package name: TO-220F)



1. T₁ Terminal
2. T₂ Terminal
3. Gate Terminal

Applications

Switching mode power supply, washing machine, motor control, heater control, and other general purpose control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	Conditions
		14		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V	$T_j = 125^\circ\text{C}$
		700		$T_j = 150^\circ\text{C}$
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	10	A	Commercial frequency, sine full wave 360° conduction, $T_c = 103^\circ\text{C}$
Surge on-state current	I_{TSM}	100	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	41.6	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	T_j	-40 to +150	°C	
Storage temperature	T_{stg}	-40 to +150	°C	
Mass	—	2.0	g	Typical value
Isolation voltage ^{Note5}	Viso	2000	V	$T_a = 25^\circ\text{C}$, AC 1 minute $T_1 \bullet T_2 \bullet G$ terminal to case

Electrical Characteristics

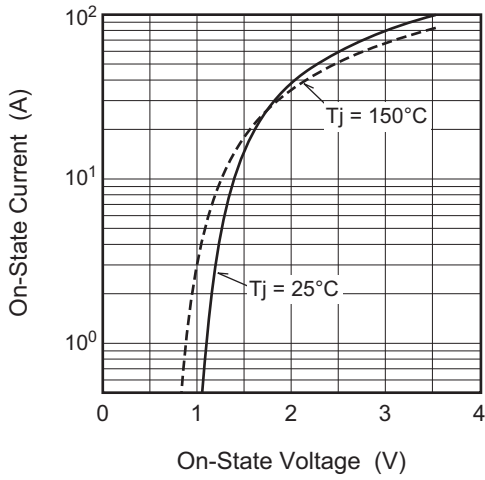
Parameter	Symbol	Rated value			Unit	Test conditions
		Min.	Typ.	Max.		
Repetitive peak off-state current	I_{DRM}	—	—	2.0	mA	$T_j = 150^\circ\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	1.5	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 15\text{A}$, instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	—	—	1.5	$T_j = 25^\circ\text{C}$, $V_D = 6\text{V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	V_{RGTI}	—	—	1.5	
	III	V_{RGTIII}	—	—	1.5	
Gate trigger current ^{Note2}	I	I_{FGTI}	—	—	30	$T_j = 25^\circ\text{C}$, $V_D = 6\text{V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	I_{RGTI}	—	—	30	
	III	I_{RGTIII}	—	—	30	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
		0.1	—	—	V	$T_j = 150^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	4.1	$^\circ\text{C}/\text{W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutation voltage ^{Note4}	$(dv/dt)_c$	10	—	—	V/ μs	$T_j = 125^\circ\text{C}$
		1	—	—	V/ μs	$T_j = 150^\circ\text{C}$

- Notes: 1. Gate open.
 2. Measurement using the gate trigger characteristics measurement circuit.
 3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is $0.5^\circ\text{C}/\text{W}$.
 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
 5. Make sure that your finished product containing this device meets your safe isolation requirements.
 For safety, it's advisable that heatsink is electrically floating.

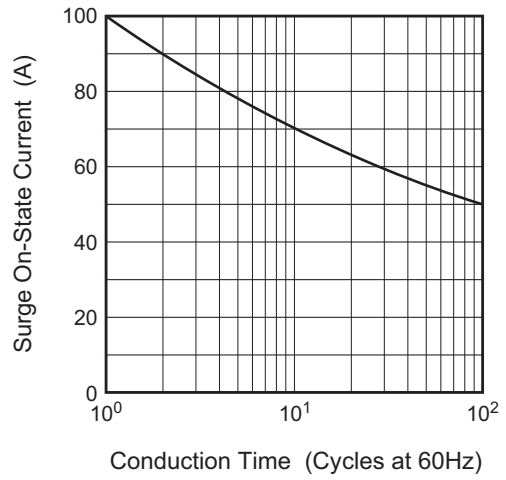
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125/150^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -5\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

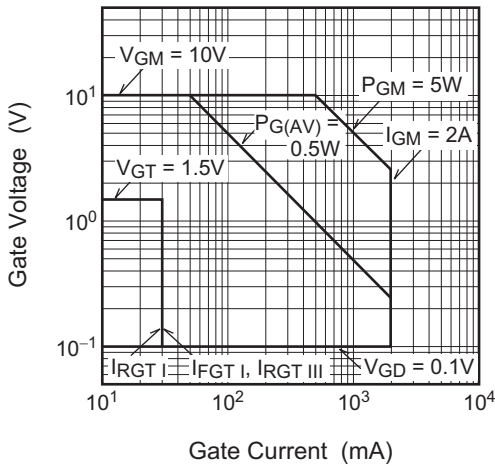
Maximum On-State Characteristics



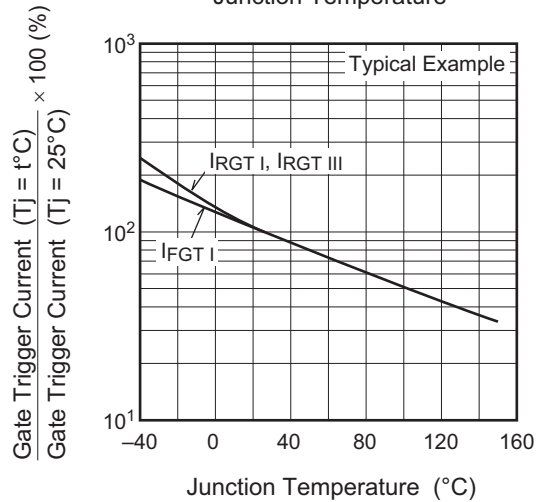
Rated Surge On-State Current



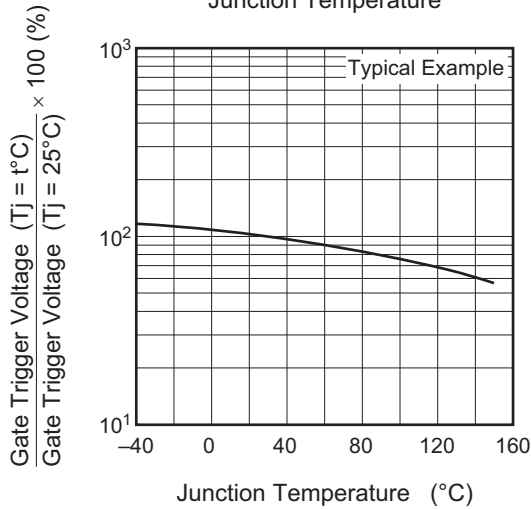
Gate Characteristics (I, II and III)



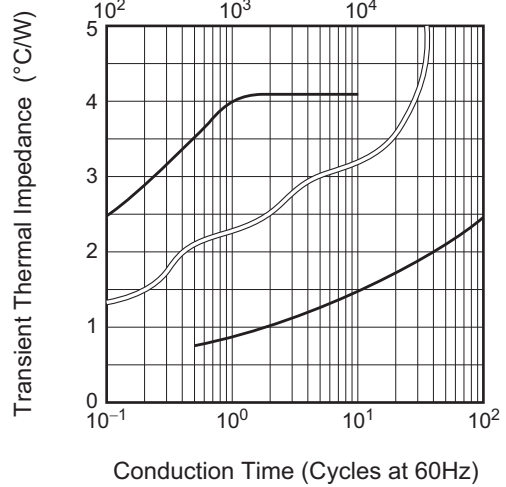
Gate Trigger Current vs. Junction Temperature

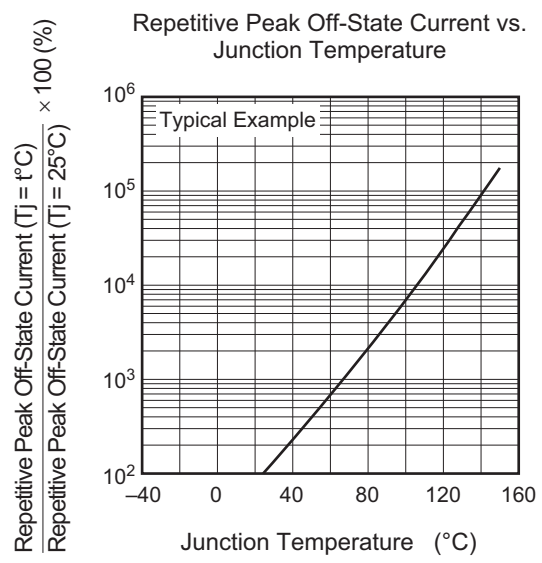
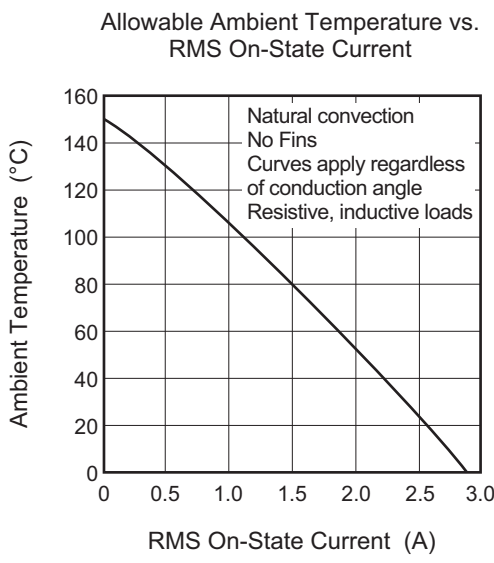
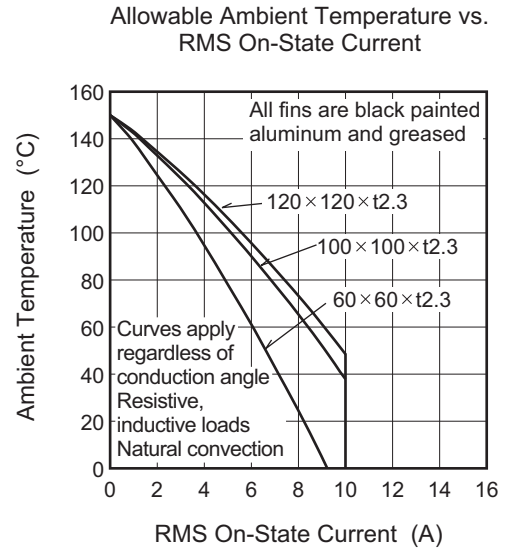
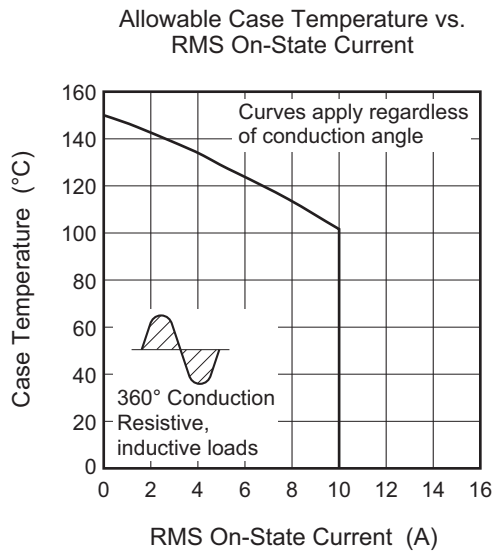
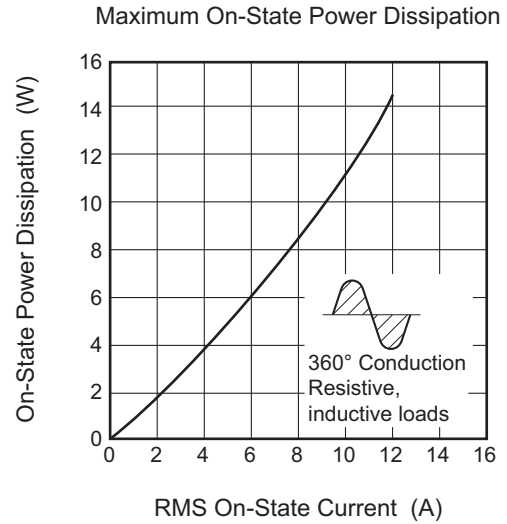
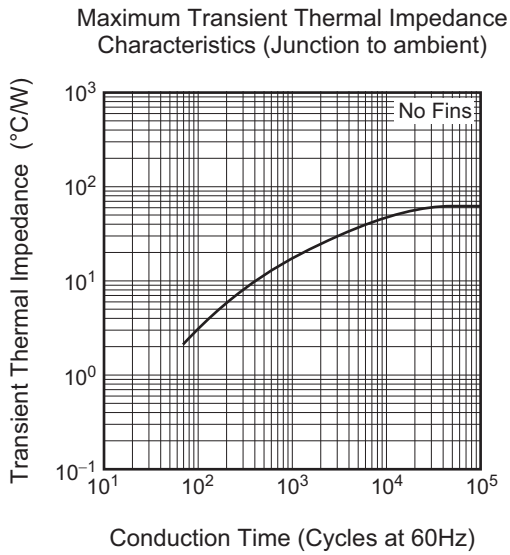


Gate Trigger Voltage vs. Junction Temperature

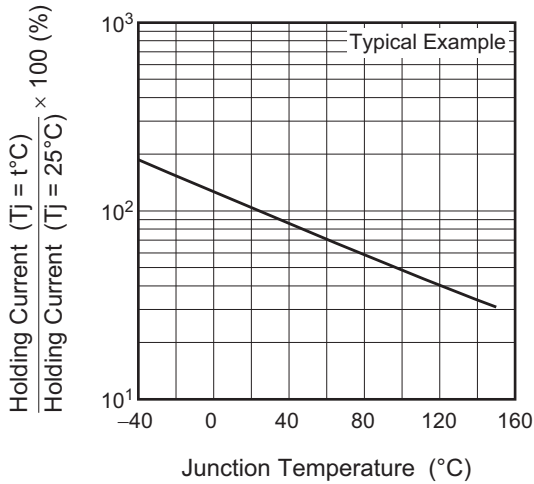


Maximum Transient Thermal Impedance Characteristics (Junction to case)

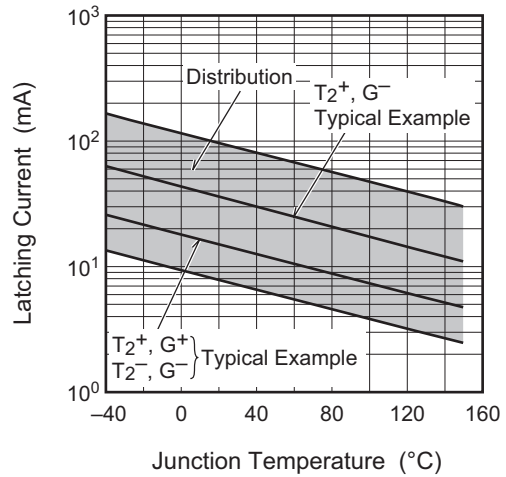




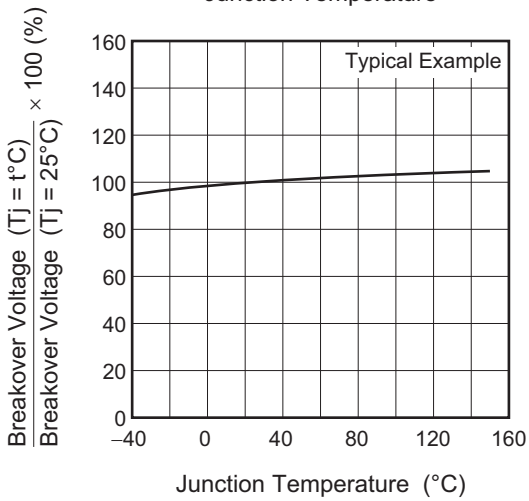
Holding Current vs. Junction Temperature



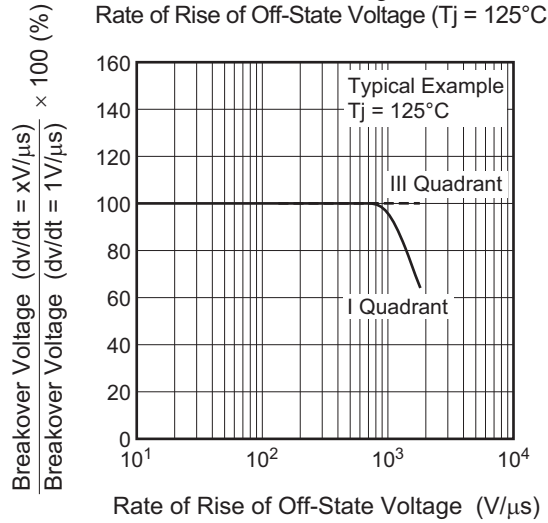
Latching Current vs. Junction Temperature



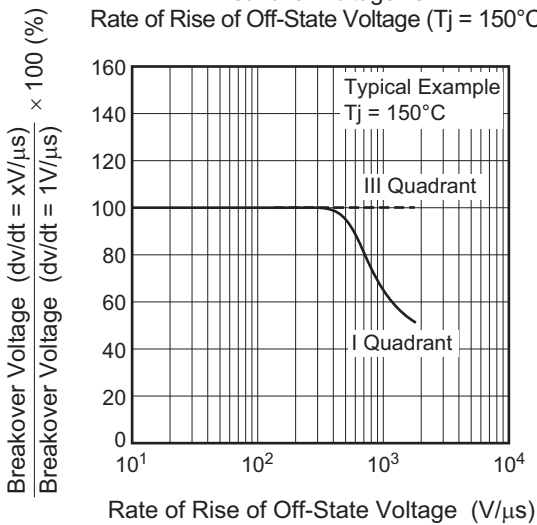
Breakover Voltage vs. Junction Temperature



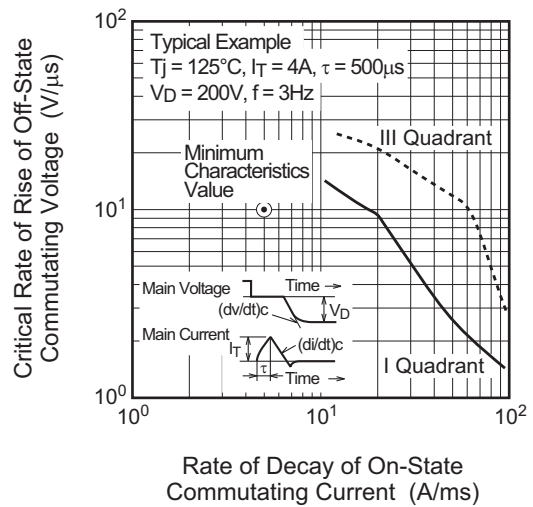
Breakover Voltage vs. Rate of Rise of Off-State Voltage (Tj = 125°C)



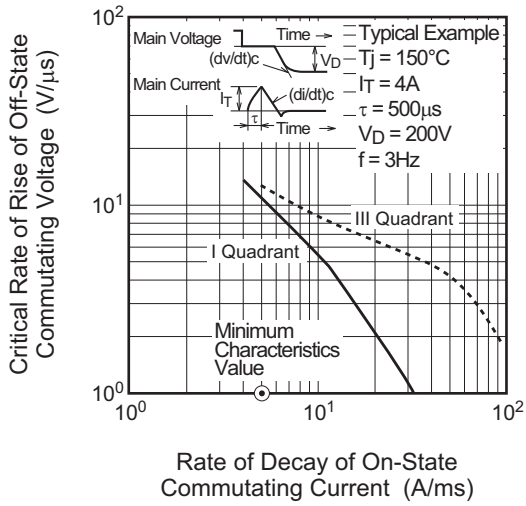
Breakover Voltage vs. Rate of Rise of Off-State Voltage (Tj = 150°C)



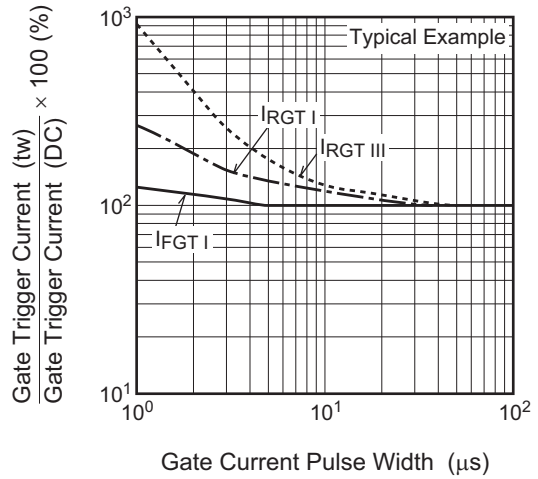
Commutation Characteristics (Tj = 125°C)



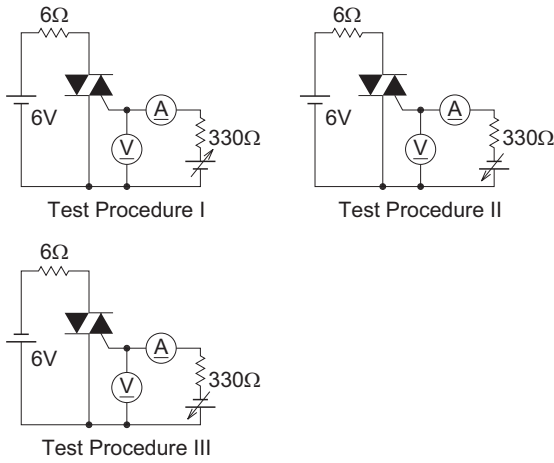
Commutation Characteristics ($T_j = 150^\circ\text{C}$)



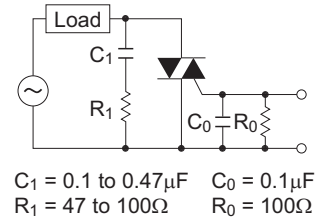
Gate Trigger Current vs. Gate Current Pulse Width



Gate Trigger Characteristics Test Circuits



Recommended Circuit Values Around The Triac



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220F	SC-67	PRSS0003AA-A	T220F	2.0g	

The technical drawing illustrates the BCR10PM-14LJ package dimensions. The top view shows a rectangular body with a diameter of 10.5 mm (maximum) and a width of 5.2 mm. The height of the body is 17 mm. The distance from the top edge to the center of the mounting hole is 5.0 mm. The mounting hole has a diameter of $\phi 3.2 \pm 0.2$ mm. The distance from the center of the mounting hole to the edge of the body is 1.2 mm. The distance from the top edge to the start of the leads is 8.5 mm. The leads are 1.3 mm (maximum) wide and 0.8 mm thick. The distance between the centers of the two leads is 2.54 mm. The total length of the leads is 13.5 mm (minimum). The distance from the top edge to the start of the leads is 3.6 mm. The distance from the top edge to the end of the leads is 2.54 mm. The side view shows a total height of 2.8 mm and a lead length of 2.6 mm. The distance from the top edge to the start of the leads is 0.5 mm. The detail view shows a width of 4.5 mm.

Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR10PM-14LJ#B00	Bag	100 pcs.	Straight type
BCR10PM-14LJA8#B00	Tube	50 pcs.	A8 Lead form

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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-3390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Laved. or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141